

200MHz, CMOS OPERATIONAL AMPLIFIER WITH SHUTDOWN

FEATURES

- **UNITY-GAIN BANDWIDTH: 450MHz**
- **WIDE BANDWIDTH: 200MHz GBW**
- **HIGH SLEW RATE: 360V/ μ s**
- **LOW NOISE: 5.8nV/ $\sqrt{\text{Hz}}$**
- **EXCELLENT VIDEO PERFORMANCE:**
DIFF GAIN: 0.02%, DIFF PHASE: 0.05°
0.1dB GAIN FLATNESS: 75MHz
- **INPUT RANGE INCLUDES GROUND**
- **RAIL-TO-RAIL OUTPUT (within 100mV)**
- **LOW INPUT BIAS CURRENT: 3pA**
- **LOW SHUTDOWN CURRENT: 3.4 μ A**
- **ENABLE/DISABLE TIME: 100ns/30ns**
- **THERMAL SHUTDOWN**
- **SINGLE-SUPPLY OPERATING RANGE: 2.5V to 5.5V**
- **MicroSIZE PACKAGES**

APPLICATIONS

- **VIDEO PROCESSING**
- **ULTRASOUND**
- **OPTICAL NETWORKING, TUNABLE LASERS**
- **PHOTODIODE TRANSIMPEDANCE AMPS**
- **ACTIVE FILTERS**
- **HIGH-SPEED INTEGRATORS**
- **ANALOG-TO-DIGITAL (A/D) CONVERTER INPUT BUFFERS**
- **DIGITAL-TO-ANALOG (D/A) CONVERTER OUTPUT AMPLIFIERS**
- **BARCODE SCANNERS**
- **COMMUNICATIONS**

DESCRIPTION

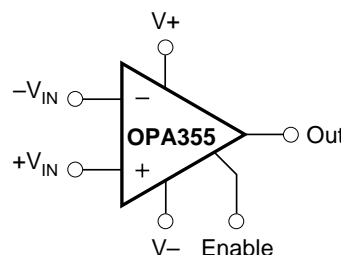
The OPAx355 series high-speed, voltage-feedback CMOS operational amplifiers are designed for video and other applications requiring wide bandwidth. The OPAx355 is unity gain stable and can drive large output currents. In addition, the OPAx355 has a digital shutdown (Enable) function. This feature provides power savings during idle periods and places the output in a high-impedance state to support output multiplexing. Differential gain is 0.02% and differential phase is 0.05°. Quiescent current is only 8.3mA per channel.

OPAx355 is optimized for operation on single or dual supplies as low as 2.5V (± 1.25 V) and up to 5.5V (± 2.75 V). Common-mode input range for the OPAx355 extends 100mV below ground and up to 1.5V from V+. The output swing is within 100mV of the rails, supporting wide dynamic range.

The OPAx355 series is available in single (SOT23-6 and SO-8), dual (MSOP-10), and triple (TSSOP-14 and SO-14) versions. Multichannel versions feature completely independent circuitry for lowest crosstalk and freedom from interaction. All are specified over the extended -40°C to 125°C range.

OPAx355 RELATED PRODUCTS

FEATURES	PRODUCT
200MHz, Rail-to-Rail Output, CMOS, No Shutdown	OPA356
38MHz, Rail-to-Rail Input/Output, CMOS	OPAx350
75MHz, Rail-to-Rail Output	OPAx631
150MHz, Rail-to-Rail Output	OPAx634
Differential Input/Output, 3.3V Supply	THS412x



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Supply Voltage, V+ to V-	7.5V
Signal Input Terminals, Voltage ⁽²⁾	(V-) - 0.5V to (V+) + 0.5V
Current ⁽²⁾	10mA
Enable Input	(V-) - 0.5V to (V+) + 0.5V
Output Short-Circuit ⁽³⁾	Continuous
Operating Temperature	-55°C to +150°C
Storage Temperature	-65°C to +150°C
Junction Temperature	+160°C
Lead Temperature (soldering, 10s)	+300°C

NOTE: (1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied. (2) Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.5V beyond the supply rails should be current limited to 10mA or less. (3) Short-circuit to ground one amplifier per package.



ELECTROSTATIC DISCHARGE SENSITIVITY

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

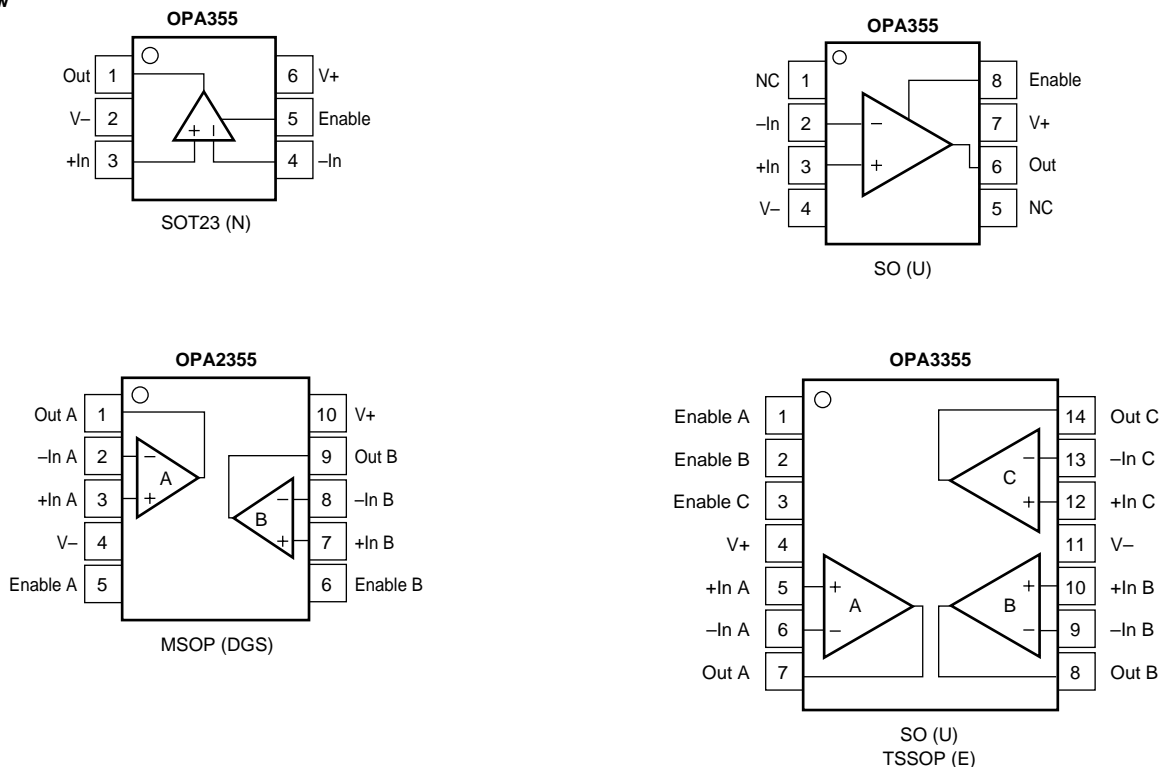
PACKAGE/ORDERING INFORMATION

PRODUCT	PACKAGE	PACKAGE DESIGNATOR	LEAD COUNT	SPECIFIED TEMPERATURE RANGE	PACKAGE MARKING	ORDERING NUMBER ⁽¹⁾	TRANSPORT MEDIA
OPA355NA	SOT23-6	DBV	6	-40°C to +125°C	C55	OPA355NA/250	Tape and Reel
"	"	"	"	"	"	OPA355NA/3K	Tape and Reel
OPA355UA	SO-8	D	8	-40°C to +125°C	OPA355UA	OPA355UA	Rails
"	"	"	"	"	"	OPA355UA/2K5	Tape and Reel
OPA2355DGSA	MSOP-10	DGS	10	-40°C to +125°C	D55	OPA2355DGSA/250	Tape and Reel
"	"	"	"	"	"	OPA2355DGSA/2K5	Tape and Reel
OPA3355EA	TSSOP-14	PW	14	-40°C to +125°C	OPA3355EA	OPA3355EA/250	Tape and Reel
"	"	"	"	"	"	OPA3355EA/2K5	Tape and Reel
OPA3355UA	SO-14	D	14	-40°C to +125°C	OPA3355UA	OPA3355UA	Rails
"	"	"	"	"	"	OPA3355UA/2K5	Tape and Reel

NOTE: (1) Models with a slash (/) are available only in Tape and Reel in the quantities indicated (e.g., /2K5 indicates 2500 devices per reel). Ordering 2500 pieces of "OPA355UA/2K5" will get a single 2500-piece Tape and Reel.

PIN CONFIGURATIONS

Top View



ELECTRICAL CHARACTERISTICS: $V_S = +2.7V$ to $+5.5V$ Single Supply

Boldface limits apply over the specified temperature range, $T_A = -40^{\circ}C$ to $+125^{\circ}C$.

At $T_A = +25^{\circ}C$, $R_F = 604\Omega$, $R_L = 150\Omega$, Connected to $V_S/2$, unless otherwise noted.

PARAMETER	CONDITION	OPA355NA, UA, OPA2355DGSA OPA3355EA, UA			UNITS
		MIN	TYP	MAX	
OFFSET VOLTAGE					
Input Offset Voltage V_{OS}	$V_S = +5V$		± 2	± 9	mV
vs Temperature dV_{OS}/dT	Specified Temperature Range		± 7	± 15	mV/ $^{\circ}C$
vs Power Supply PSRR	$V_S = +2.7V$ to $+5.5V$, $V_{CM} = V_S/2 - 0.15V$		± 80	± 350	$\mu V/V$
INPUT BIAS CURRENT					
Input Bias Current I_B			3	± 50	pA
Input Offset Current I_{OS}			± 1	± 50	pA
NOISE					
Input Noise Voltage Density e_n	$f = 1MHz$		5.8		nV/ \sqrt{Hz}
Current Noise Density i_n	$f = 1MHz$		50		fA/ \sqrt{Hz}
INPUT VOLTAGE RANGE					
Common-Mode Voltage Range V_{CM}	$V_S = +5.5V$, $-0.1V < V_{CM} < +4.0V$	$(V-) - 0.1$		$(V+) - 1.5$	V
Common-Mode Rejection Ratio CMRR	Specified Temperature Range	66	80		dB
		66			dB
INPUT IMPEDANCE					
Differential			$10^{13} \parallel 1.5$		$\Omega \parallel pF$
Common-Mode			$10^{13} \parallel 1.5$		$\Omega \parallel pF$
OPEN-LOOP GAIN					
	$V_S = +5V$, $0.3V < V_O < 4.7V$	84	92		dB
OPA355	$V_S = +5V$, $0.3V < V_O < 4.7V$	80			dB
OPA2355, OPA3355	$V_S = +5V$, $0.4V < V_O < 4.6V$	80			dB
FREQUENCY RESPONSE					
Small-Signal Bandwidth f_{-3dB}	$G = +1$, $V_O = 100mVp-p$, $R_F = 0\Omega$		450		MHz
f_{-3dB}	$G = +2$, $V_O = 100mVp-p$, $R_L = 50\Omega$		100		MHz
f_{-3dB}	$G = +2$, $V_O = 100mVp-p$, $R_L = 150\Omega$		170		MHz
f_{-3dB}	$G = +2$, $V_O = 100mVp-p$, $R_L = 1k\Omega$		200		MHz
Gain-Bandwidth Product GBW	$G = +10$, $R_L = 1k\Omega$		200		MHz
Bandwidth for 0.1dB Gain Flatness $f_{0.1dB}$	$G = +2$, $V_O = 100mVp-p$, $R_F = 560\Omega$		75		MHz
Slew Rate SR	$V_S = +5V$, $G = +2$, 4V Output Step		300/–360		V/ μs
Rise-and-Fall Time	$G = +2$, $V_O = 200mVp-p$, 10% to 90%		2.4		ns
	$G = +2$, $V_O = 2Vp-p$, 10% to 90%		8		ns
Settling Time, 0.1%	$V_S = +5V$, $G = +2$, 2V Output Step		30		ns
0.01%	$V_S = +5V$, $G = +2$, 2V Output Step		120		ns
Overload Recovery Time	$V_{IN} \bullet \text{Gain} = V_S$		8		ns
Harmonic Distortion					
2 nd Harmonic	$G = +2$, $f = 1MHz$, $V_O = 2Vp-p$, $R_L = 200\Omega$		–81		dBc
3 rd Harmonic	$G = +2$, $f = 1MHz$, $V_O = 2Vp-p$, $R_L = 200\Omega$		–93		dBc
Differential Gain Error	NTSC, $R_L = 150\Omega$		0.02		%
Differential Phase Error	NTSC, $R_L = 150\Omega$		0.05		degrees
Channel-to-Channel Crosstalk OPA2355	$f = 5MHz$		–90		dB
OPA3355	$f = 5MHz$		–70		dB
OUTPUT					
Voltage Output Swing from Rail	$V_S = +5V$, $R_L = 150\Omega$, $A_{OL} > 84dB$		0.2	0.3	V
Voltage Output Swing from Rail	$V_S = +5V$, $R_L = 1k\Omega$		0.1		V
Output Current, Continuous ⁽¹⁾ I_O			± 60		mA
Output Current, Peak ⁽¹⁾ I_O	$V_S = +5V$		± 100		mA
Output Current, Peak ⁽¹⁾ I_O	$V_S = +3V$		± 80		mA
Closed-Loop Output Impedance	$f < 100kHz$		0.02		Ω
POWER SUPPLY					
Specified Voltage Range V_S		2.7		5.5	V
Operating Voltage Range			2.5 to 5.5		V
Quiescent Current (per amplifier) I_Q	$V_S = +5V$, Enabled, $I_O = 0$		8.3	11	mA
	Specified Temperature Range			14	mA

ELECTRICAL CHARACTERISTICS: $V_S = +2.7V$ to $+5.5V$ Single Supply (Cont.)

Boldface limits apply over the specified temperature range, $T_A = -40^{\circ}C$ to $+125^{\circ}C$.

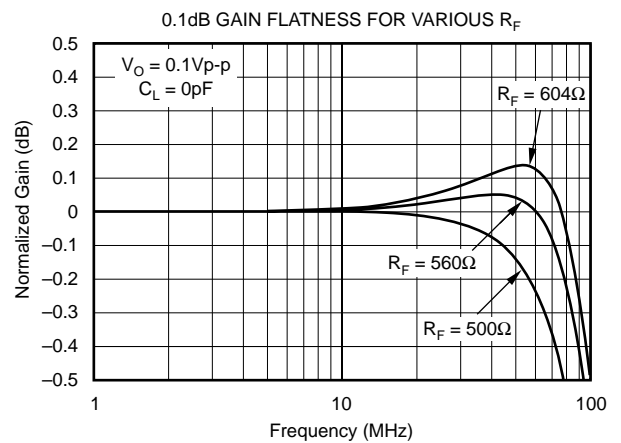
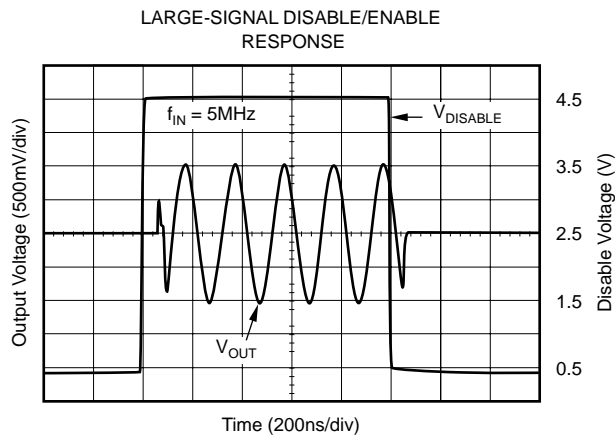
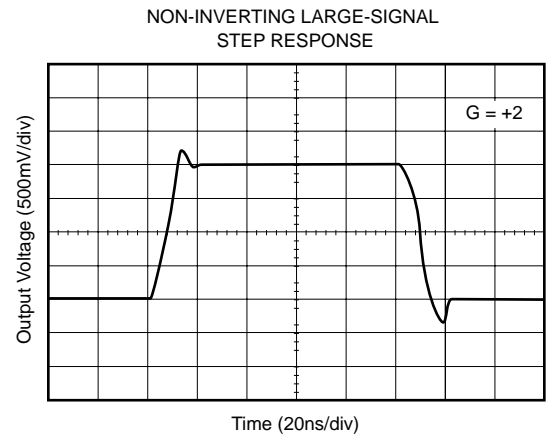
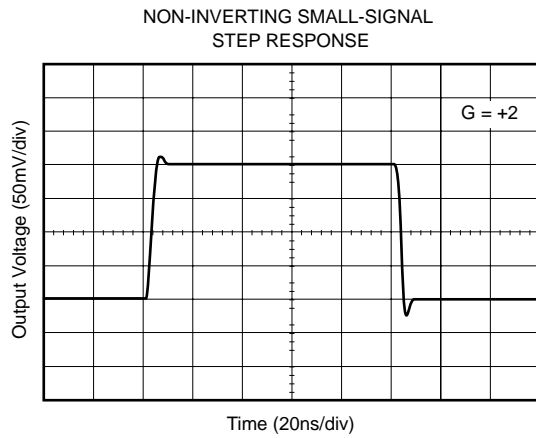
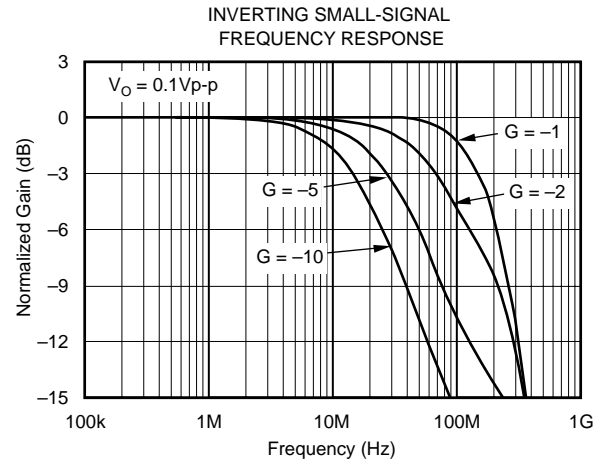
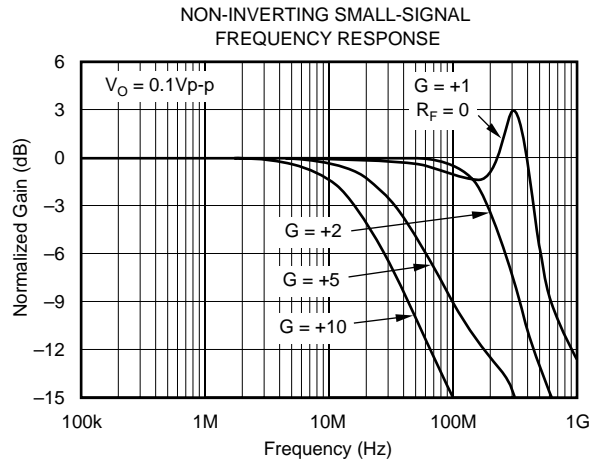
At $T_A = +25^{\circ}C$, $R_F = 604\Omega$, $R_L = 150\Omega$, Connected to $V_S/2$, unless otherwise noted.

PARAMETER	CONDITION	OPA355NA, UA, OPA2355DGSA OPA3355EA, UA			UNITS
		MIN	TYP	MAX	
SHUTDOWN					
Disable (Logic-Low Threshold) ⁽²⁾				0.8	V
Enable (Logic-High Threshold) ⁽²⁾		2			V
Enable Time			100		ns
Disable Time			30		ns
Shutdown Current (per amplifier)	$V_S = +5V$, Disabled		3.4	6	μA
THERMAL SHUTDOWN					
Junction Temperature					
Shutdown			160		$^{\circ}C$
Reset from Shutdown			140		$^{\circ}C$
TEMPERATURE RANGE					
Specified Range		-40		125	$^{\circ}C$
Operating Range		-55		150	$^{\circ}C$
Storage Range		-65		150	$^{\circ}C$
Thermal Resistance θ_{JA}					$^{\circ}C/W$
SOT-23-6, MSOP-10			150		$^{\circ}C/W$
SO-8			125		$^{\circ}C/W$
SO-14, TSSOP-14			100		$^{\circ}C/W$

NOTES: (1) See typical performance characteristic "Output Voltage Swing vs Output Current." (2) Logic Low and High levels are CMOS logic compatible.

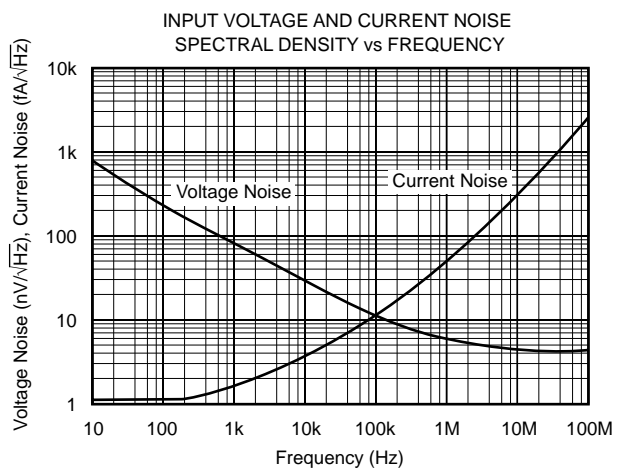
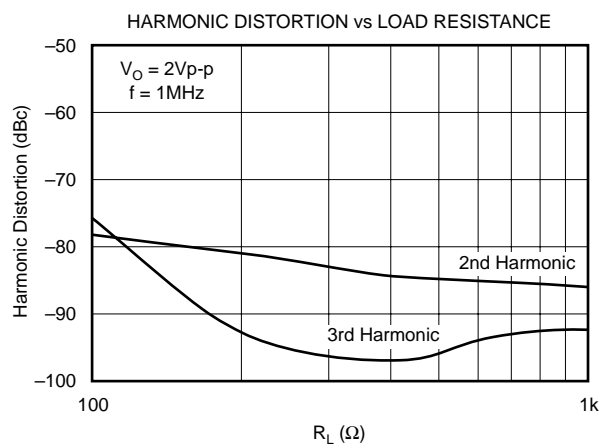
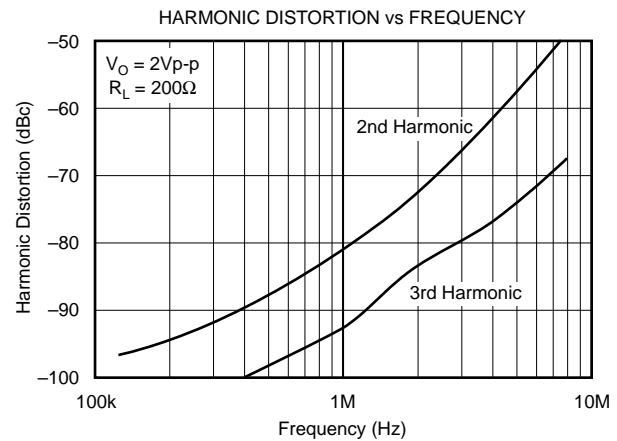
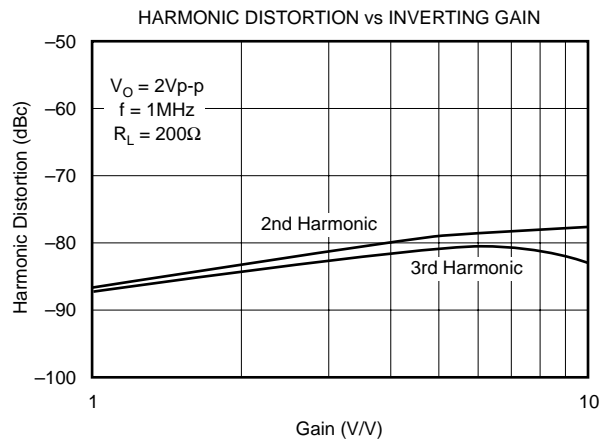
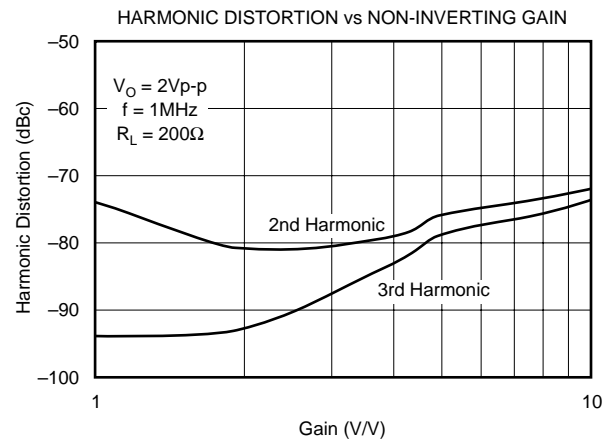
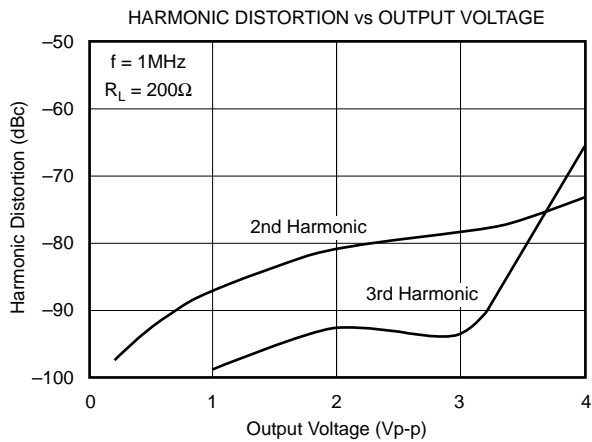
TYPICAL CHARACTERISTICS

At $T_A = +25^\circ\text{C}$ and $V_S = 5\text{V}$, $G = +2$, $R_F = 604\Omega$, $R_L = 150\Omega$ connected to $V_S/2$, unless otherwise noted.



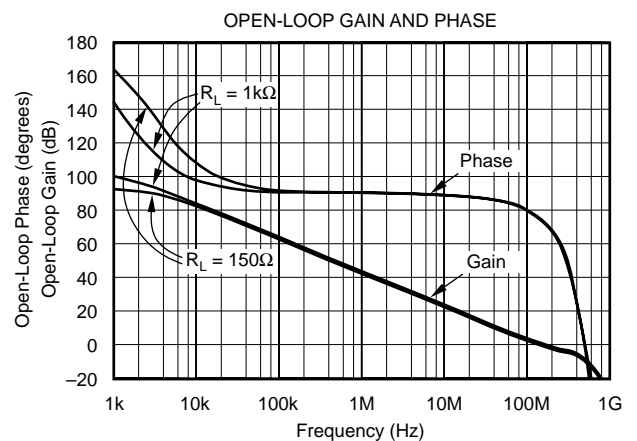
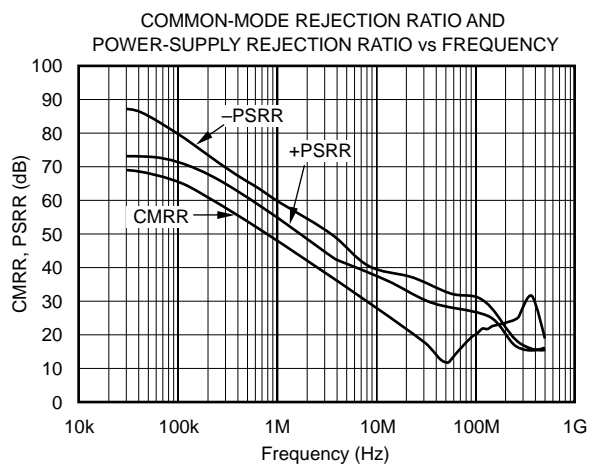
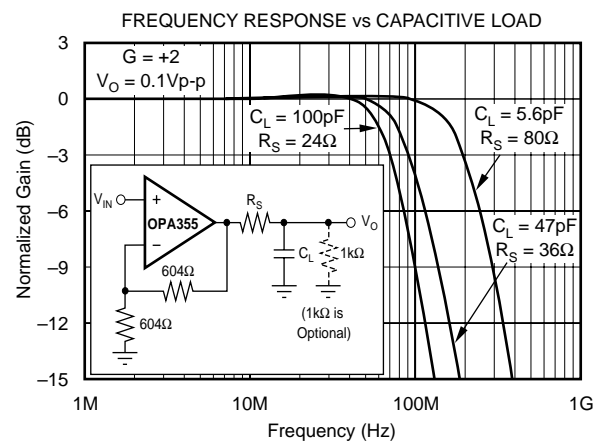
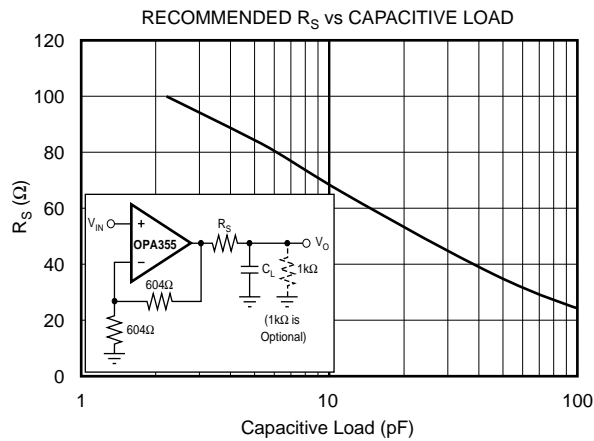
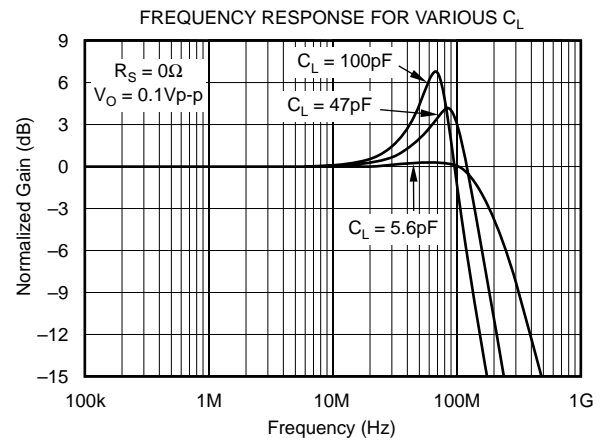
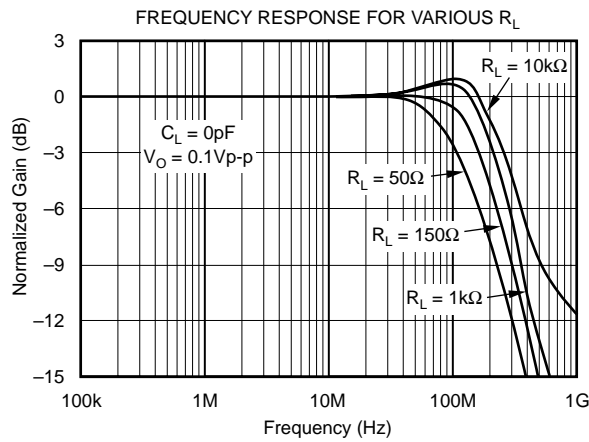
TYPICAL CHARACTERISTICS (Cont.)

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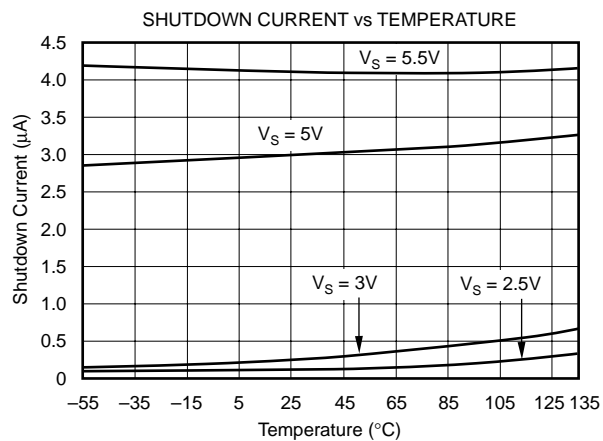
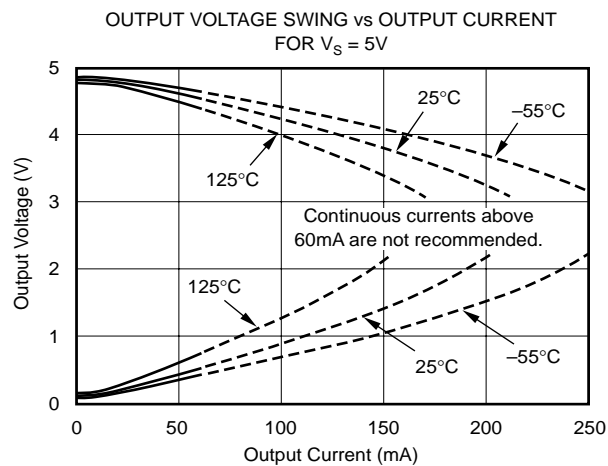
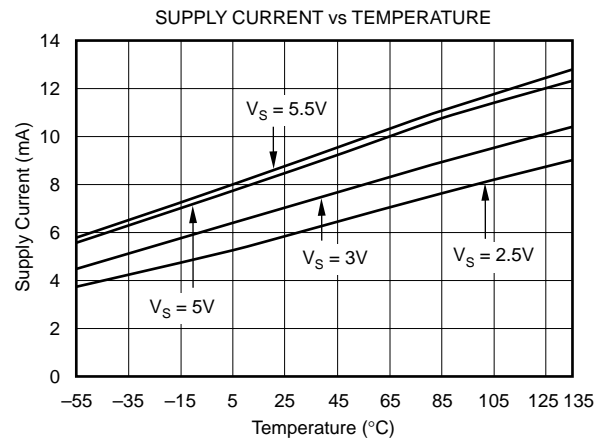
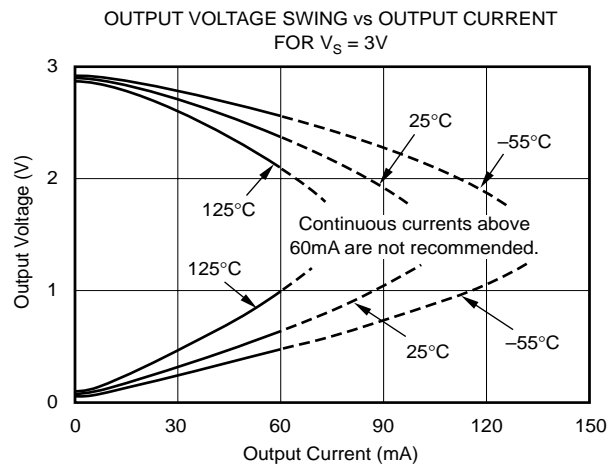
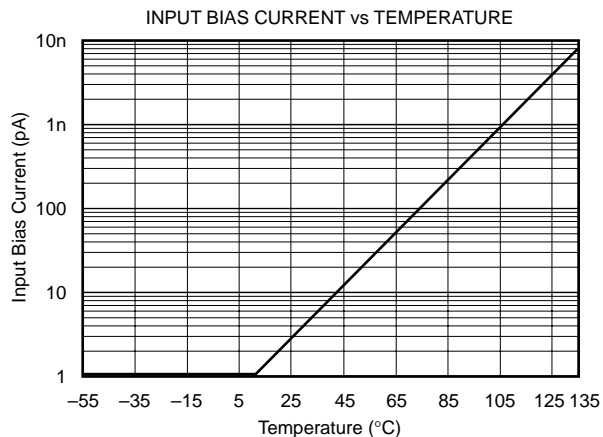
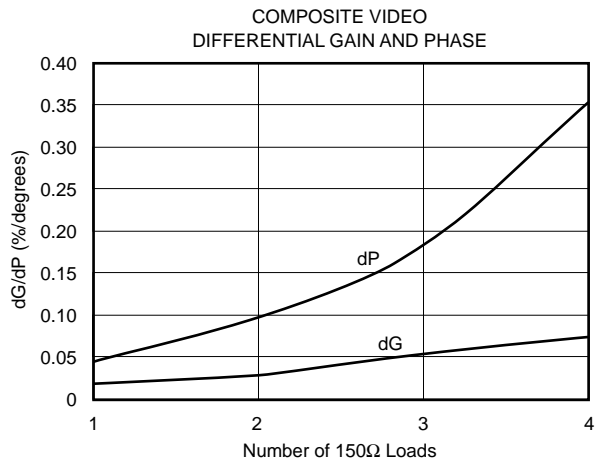
TYPICAL CHARACTERISTICS (Cont.)

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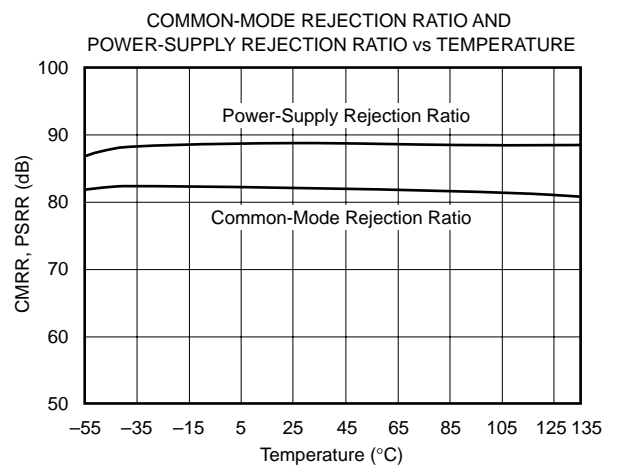
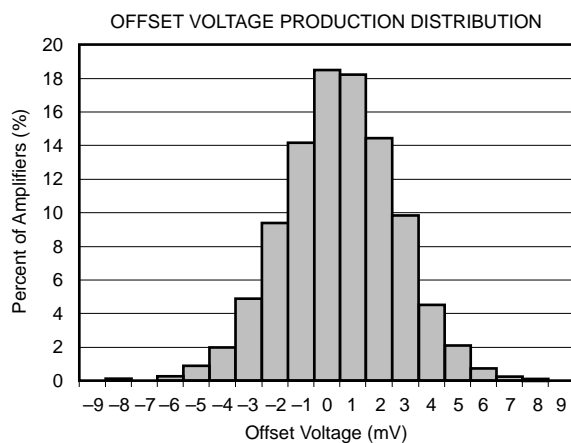
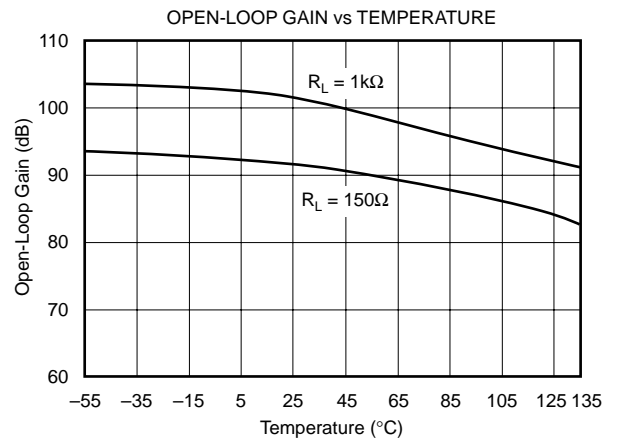
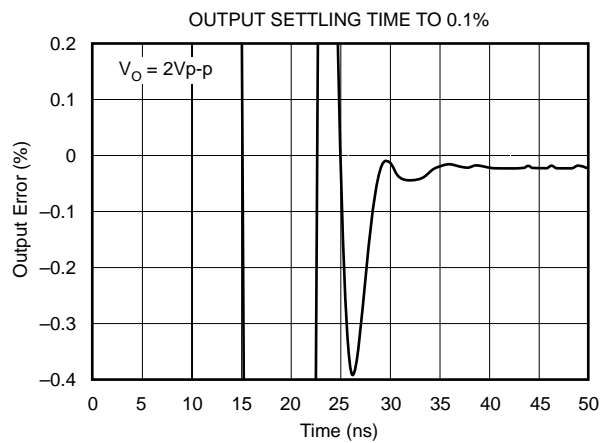
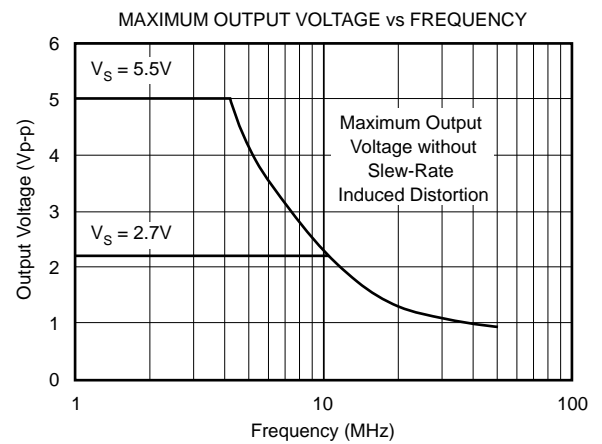
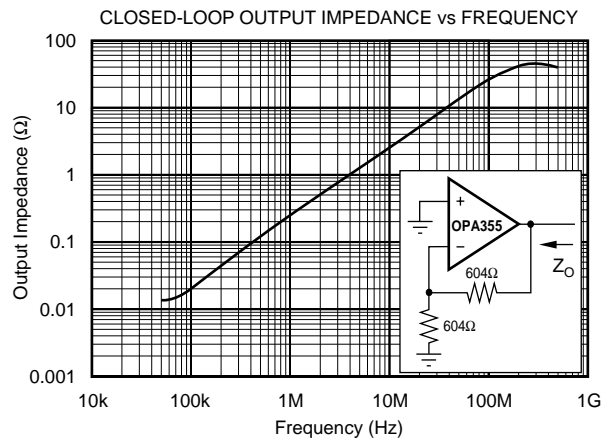
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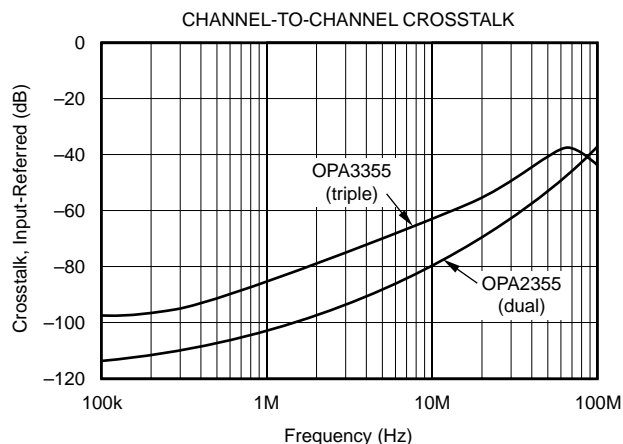
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TYPICAL CHARACTERISTICS (Cont.)

At $T_A = +25^\circ\text{C}$ and $V_S = 5\text{V}$, $G = +2$, $R_F = 604\Omega$, $R_L = 150\Omega$ connected to $V_S/2$, unless otherwise noted.



APPLICATIONS INFORMATION

The OPAx355 series is a CMOS, high-speed, voltage feed-back, operational amplifier designed for video and other general-purpose applications. It is available as a single, dual, or triple op amp.

The amplifier features a 200MHz gain bandwidth and 360V/ μs slew rate, but it is unity-gain stable and can be operated as a +1V/V voltage follower.

Its input common-mode voltage range includes ground, allowing the OPAx355 to be used in virtually any single-supply application up to a supply voltage of +5.5V.

PCB LAYOUT

Good high-frequency PC board layout techniques should be employed for the OPAx355. Generous use of ground planes, short direct signal traces, and a suitable bypass capacitor located at the $V+$ pin will assure clean, stable operation. Large areas of copper also provide a means of dissipating heat that is generated within the amplifier in normal operation.

Sockets are definitely not recommended for use with any high-speed amplifier.

A 10 μF ceramic bypass capacitor is the minimum recommended value; adding a 1 μF or larger tantalum capacitor in

parallel can be beneficial when driving a low-resistance load. Providing adequate bypass capacitance is essential to achieving very low harmonic and intermodulation distortion.

OPERATING VOLTAGE

The OPAx355 is specified over a power-supply range of +2.7V to +5.5V (± 1.35 to $\pm 2.75\text{V}$). However, the supply voltage may range from +2.5V to +5.5V ($\pm 1.25\text{V}$ to $\pm 2.75\text{V}$). Supply voltages higher than 7.5V (absolute maximum) can permanently damage the amplifier.

Parameters that vary significantly over supply voltage or temperature are shown in the "Typical Characteristics" section of this data sheet.

ENABLE FUNCTION

The OPAx355 can be enabled by applying a TTL "High" voltage level to the Enable pin. Conversely, a TTL "Low" voltage level will disable the amplifier, reducing its supply current from 8.3mA to only 3.4 μA per amplifier. Independent Enable pins are available for each channel, providing maximum design flexibility. For portable battery-operated applications, this feature can be used to greatly reduce the average current and thereby extend battery life.

The Enable input can be modeled as a CMOS input gate with a 100k Ω pull-up resistor to V+. Left open, the Enable pin will assume a logic “High”, and the amplifier will be on.

The Enable time is 100ns and the disable time is only 30ns. This allows the OPAx355 to be operated as a “gated” amplifier, or to have its output multiplexed onto a common output bus. When disabled, the output assumes a high-impedance state.

OUTPUT DRIVE

The OPAx355 output stage is capable of driving a standard back-terminated 75 Ω video cable. By back-terminating a transmission line, it does not exhibit a capacitive load to its driver. A properly back-terminated 75 Ω cable does not appear as capacitance; it presents only a 150 Ω resistive load to the OPAx355 output.

The output stage can supply high short-circuit current (typically over 200mA). Therefore, an on-chip thermal shutdown circuit is provided to protect the OPAx355 from dangerously high junction temperatures. At 160°C, the protection circuit will shut down the amplifier. Normal operation will resume when the junction temperature cools to below 140°C.

NOTE: it is not recommended to run a continuous DC current in excess of ± 60 mA. Refer to the Typical Characteristics’ “Output Voltage Swing vs Output Current”.

INPUT AND ESD PROTECTION

All OPAx355 pins are static protected with internal ESD protection diodes tied to the supplies, as shown in Figure 1.

These diodes will provide overdrive protection if the current is externally limited to 10mA by the source or by a resistor.

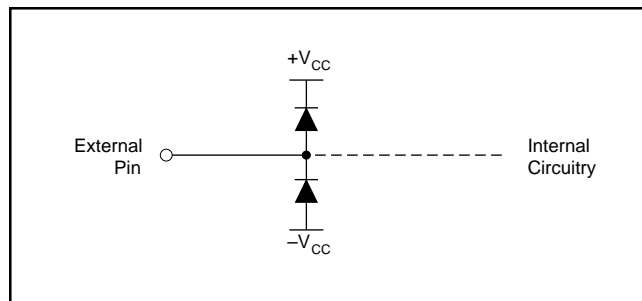
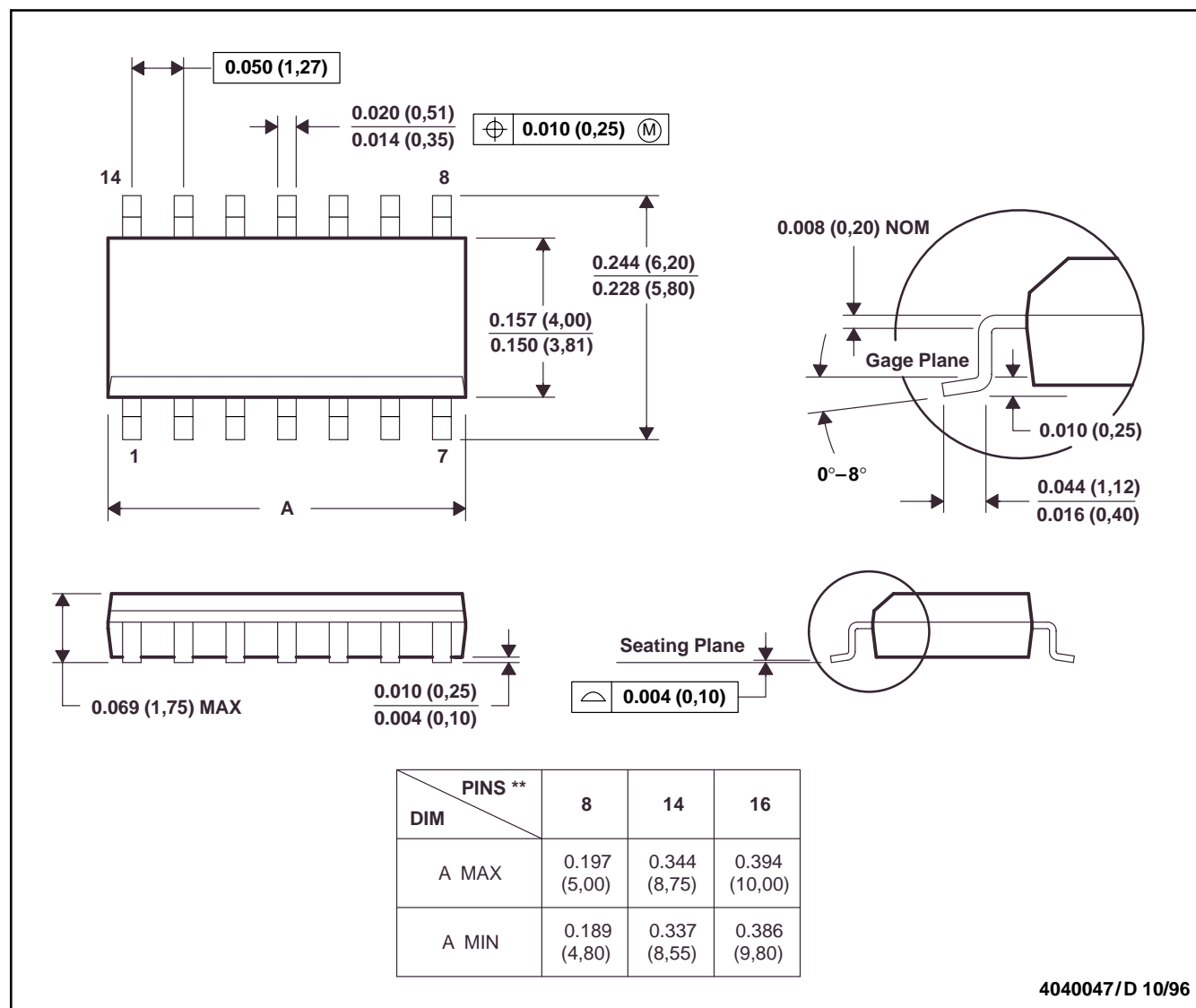


FIGURE 1. Internal ESD Protection.

D (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

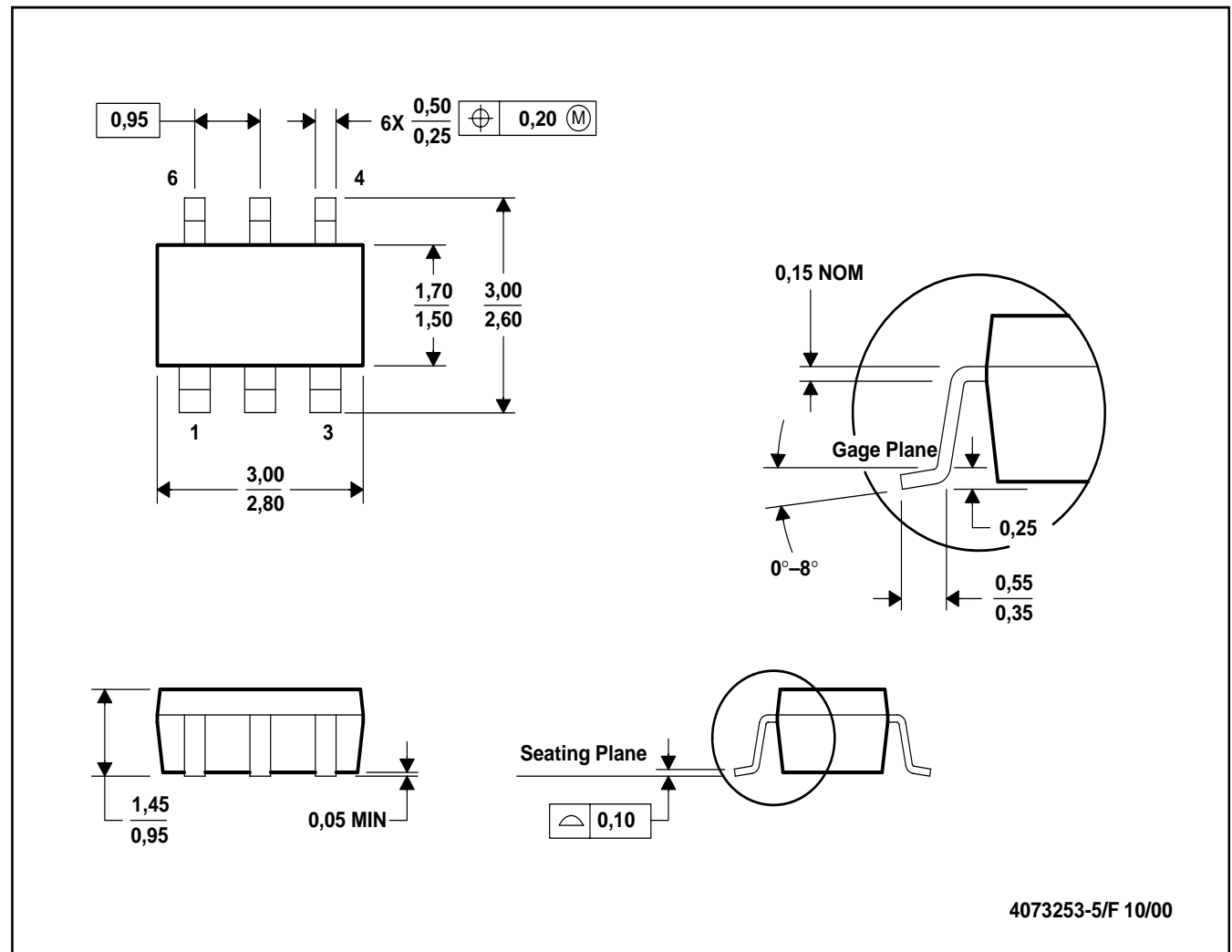
14 PINS SHOWN



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).
 - D. Falls within JEDEC MS-012

DBV (R-PDSO-G6)

PLASTIC SMALL-OUTLINE

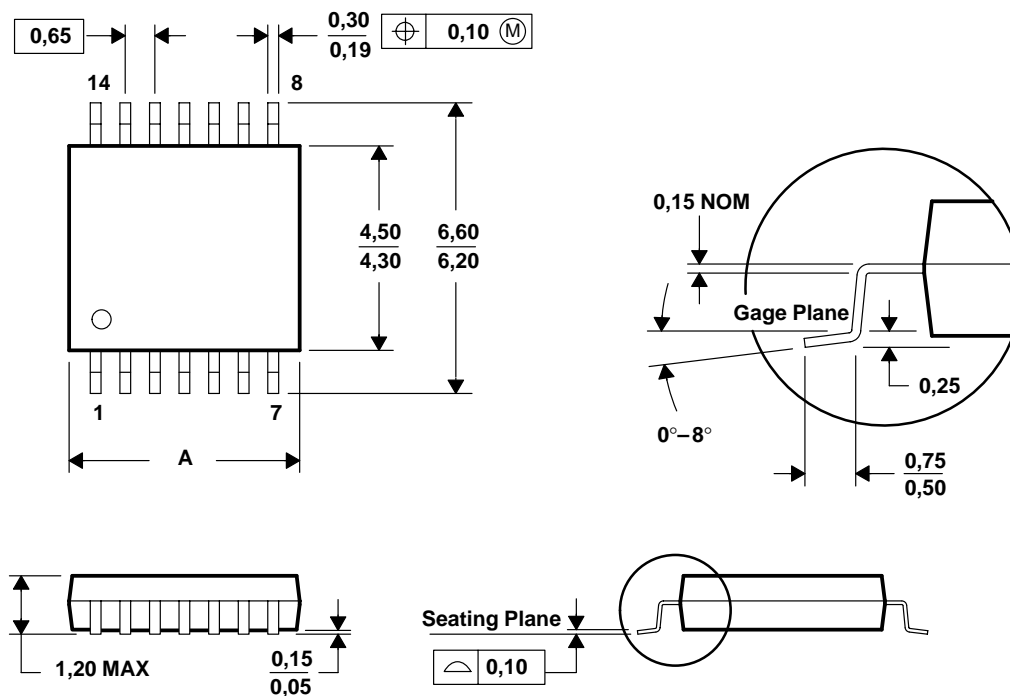


- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion.
 - D. Leads 1, 2, 3 are wider than leads 4, 5, 6 for package orientation.

PW (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



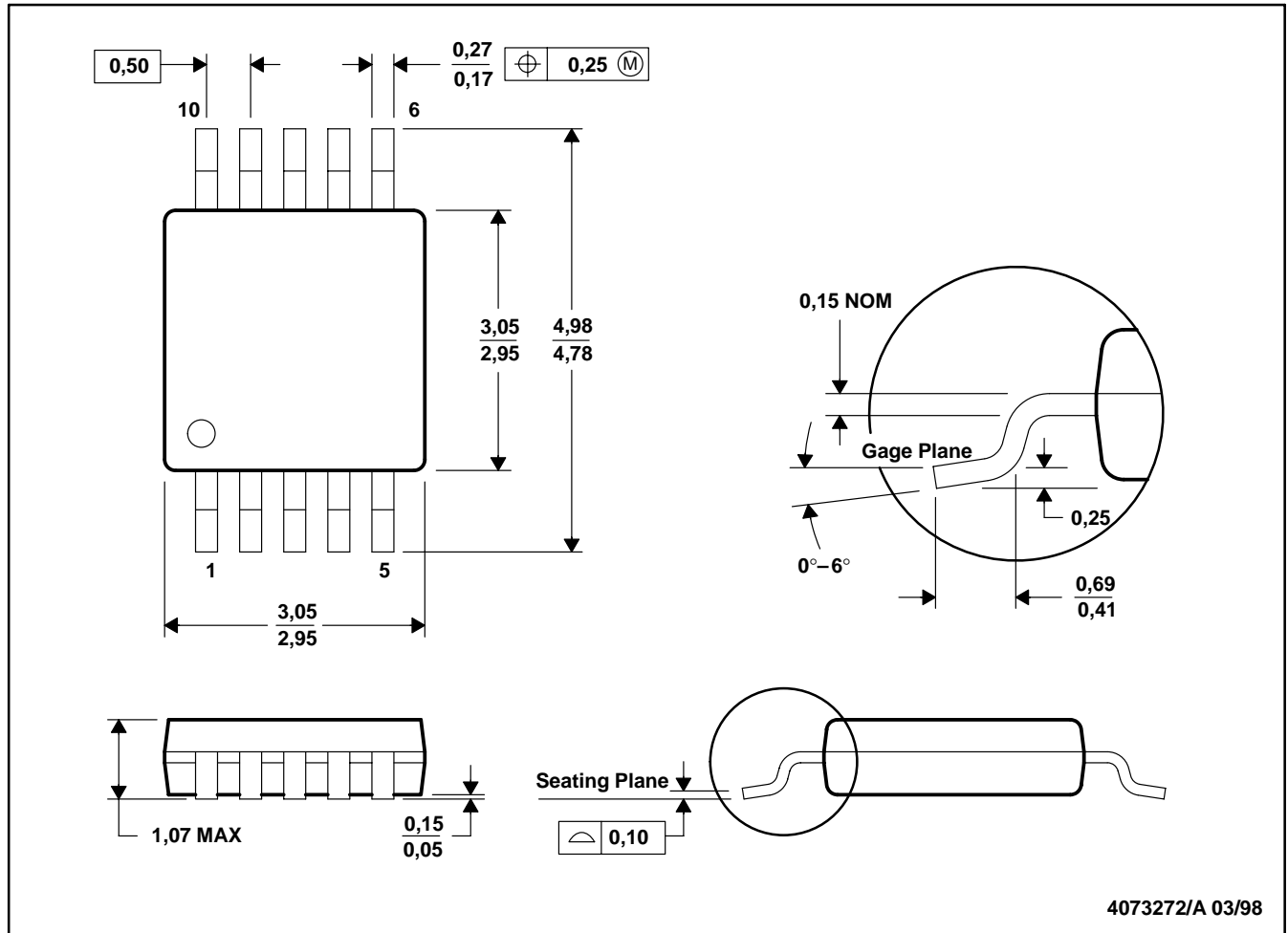
PINS **	8	14	16	20	24	28
DIM						
A MAX	3,10	5,10	5,10	6,60	7,90	9,80
A MIN	2,90	4,90	4,90	6,40	7,70	9,60

4040064/F 01/97

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
 - D. Falls within JEDEC MO-153

DGS (S-PDSO-G10)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion.

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